

PRODUCT CHARACTERISTICS

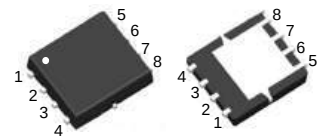
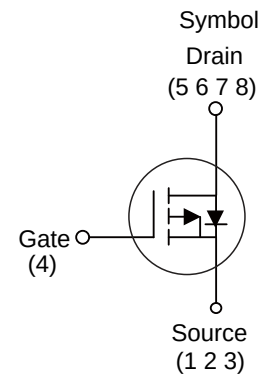
V_{DSS}	-15V
$R_{DS(ON)} Typ(@V_{GS}=-4.5V)$	8.3m Ω
$R_{DS(ON)} Typ(@V_{GS}=-2.5V)$	11.5m Ω
I_D	-55A

APPLICATIONS

- * Electronic lamp ballasts based on half bridge
- * Load Switching, Quick/Wireless Charge.
- * Motor Driving

FEATURE

- * Low Gate Charge
- * Pb-Free Lead Plating



PDFN3X3

ORDER INFORMATION

Order Codes		Package	Packing
Halogen-Free	Halogen		
N/A	MOT2319J	PDFN3X3	5000 pieces/Reel

ABSOLUTE MAXIMUM RATINGS($T_A=25^{\circ}C$, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Drain-Source Voltage	V_{DSS}	-15	V
Gate-Source Voltage	V_{GSS}	± 12	V
Drain Current Continuous($@V_{GS}=-4.5V, T_A=25^{\circ}C$)	I_D	-55	A
Drain Current Continuous($@V_{GS}=-4.5V, T_A=100^{\circ}C$)	I_D	-35	A
Drain Current Pulsed	I_{DM}	-220	A
Avalanche Energy *	E_{AS}	100	mJ
Power Dissipation	P_D	66	W
Junction Temperature	T_J	+150	$^{\circ}C$
Storage Temperature	T_{STG}	-55~ +150	$^{\circ}C$

THERMAL CHARACTERISTICS

Parameter	Symbol	Typ	Unit
Junction to Case	R_{thJC}	1.89	$^{\circ}C/W$

Note: * EAS condition: $T_J=25^{\circ}C, V_{DD}=12V, V_G=10V, L=0.5mH, R_g=25\Omega$

■ ELECTRICAL CHARACTERISTICS ($T_C=25^{\circ}\text{C}$, unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Off characteristics						
Drain to Source Breakdown Voltage	V _{DSS}	V _{GS} =0V,I _D =-250μA	-15	-	-	V
Drain to Source Leakage Current	I _{DSS}	V _{DS} =-15V,V _{GS} =0V	-	-	-1	μA
Gate to Source Forward Leakage	I _{GSS(F)}	V _{GS} =+12V,V _{DS} =0V	-	-	100	nA
Gate to Source Reverse Leakage	I _{GSS(R)}	V _{GS} =-12V ,V _{DS} =0V	-	-	-100	nA
On characteristics						
Drain to Source On-Resistance	R _{DS(ON)}	V _{GS} =-4.5V,I _D =-15A	-	8.3	13	mΩ
		V _{GS} =-2.5V,I _D =-12A	-	11.5	16	mΩ
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} ,I _D =-250μA	-0.3	-0.65	-1.5	V
Dynamic characteristics						
Gate Resistance	R _g	V _{GS} =0V,V _{DS} =0V ,f=1.0MHz	-	17.8	-	Ω
Forward Transconductance	g _{fs}	V _{DS} =-10V,I _D =-3A	4	-	-	S
Input Capacitance	C _{iss}	V _{DS} =-12V,V _{GS} =0V f=1.0MHz	-	2100	-	pF
Output Capacitance	C _{oss}		-	350	-	pF
Reverse Transfer Capacitance	C _{rss}		-	300	-	pF
Resistive Switching Characteristics						
Turn-on Delay Time	t _{d(ON)}	V _{GS} =-4.5V,V _{DS} =-10V, I _D =-15A ,R _G =13Ω	-	11	-	ns
Rise Time	t _r		-	110	-	ns
Turn-off Delay Time	t _{d(OFF)}		-	157	-	ns
Fall Time	t _f		-	160	-	ns
Total Gate Charge	Q _g	I _D =-15A, V _{DS} =-10V V _{GS} =-4.5V	-	56	-	nC
Gate to Source Charge	Q _{gs}		-	8	-	nC
Gate to Drain("Miller") Charge	Q _{gd}		-	16	-	nC
Source-Drain Diode Characteristics						
Continuous Source Current(Body Diode)	I _s		-	-	-55	A
Maximum Pulsed Current(Body Diode)	I _{SM}		-	-	-220	A
Diode Forward Voltage	V _{SD}	I _{SD} =-1A, V _{GS} =0V	-	-0.72	-1.2	V
Reverse Recovery Time	t _{rr}	I _{SD} =-15A, T _J =25℃ dI/dt=100A/μs	-	23	-	ns
Reverse Recovery Charge	Q _{rr}		-	14	-	nC

■ TYPICAL CHARACTERISTICS

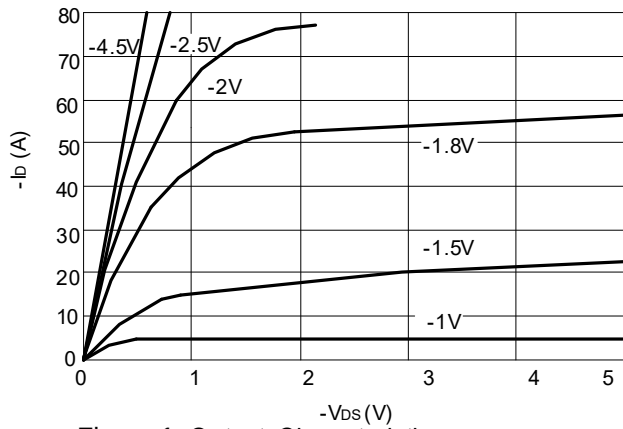


Figure 1: Output Characteristics

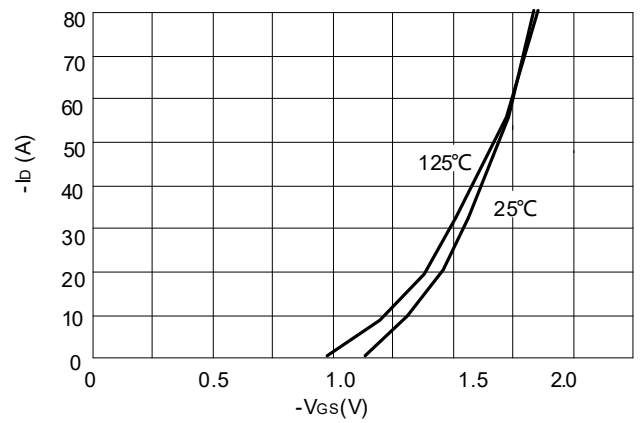


Figure 2: Typical Transfer Characteristics

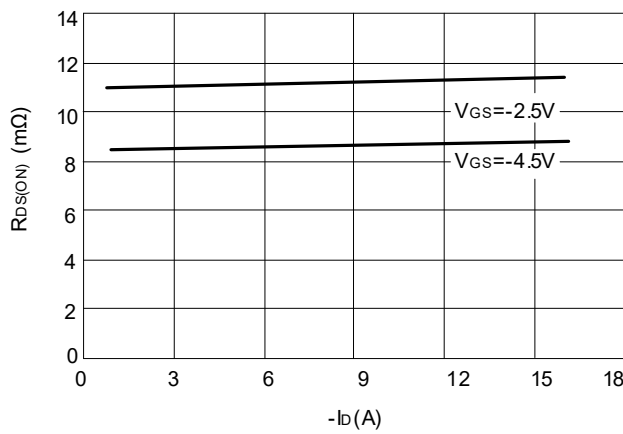


Figure 3: On-resistance vs. Drain Current

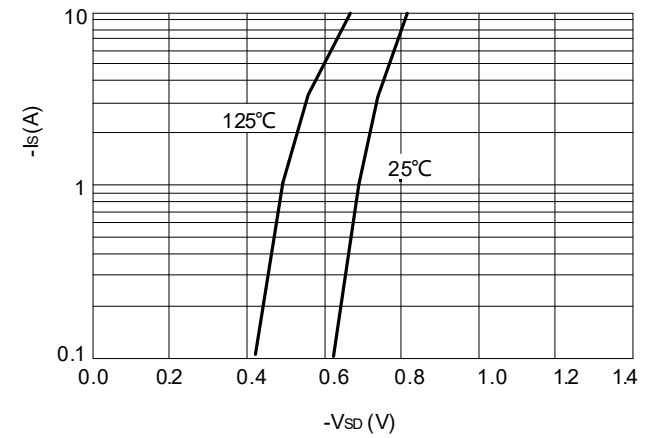


Figure 4: Body Diode Characteristics

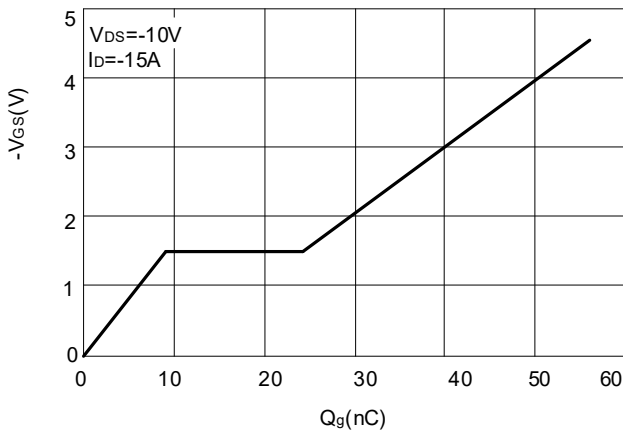


Figure 5: Gate Charge Characteristics

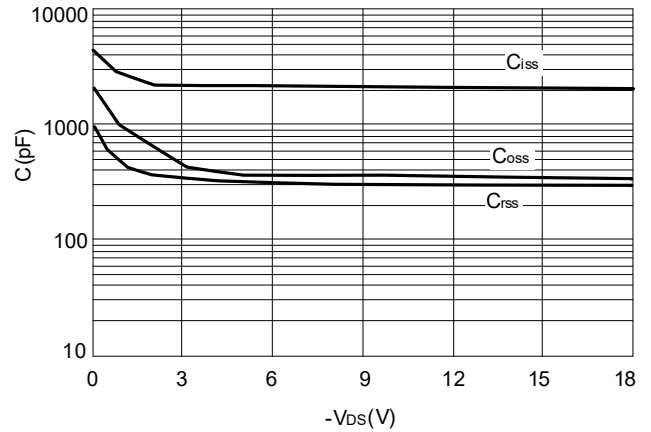


Figure 6: Capacitance Characteristics

■ TYPICAL CHARACTERISTICS(Cont.)

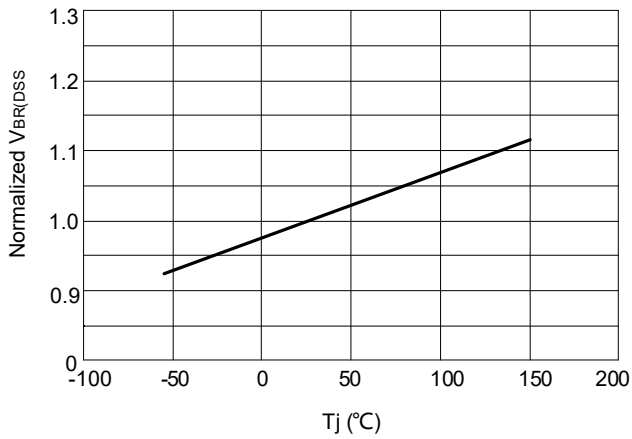


Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

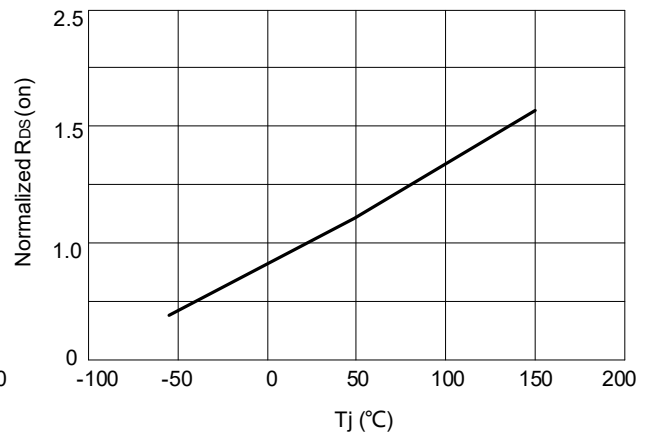


Figure 8: Normalized on Resistance vs. Junction Temperature

Limited by $R_{DS(on)}$

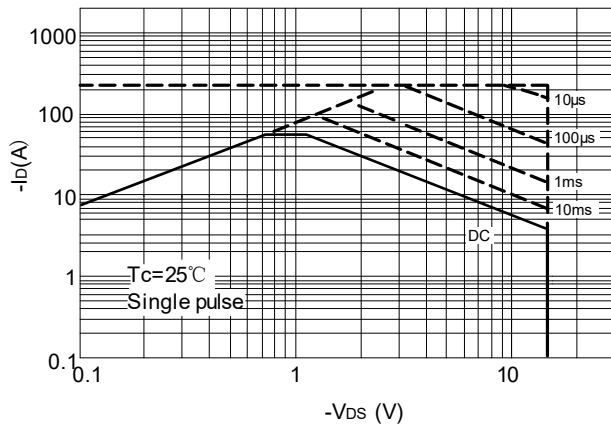


Figure 9: Maximum Safe Operating Area

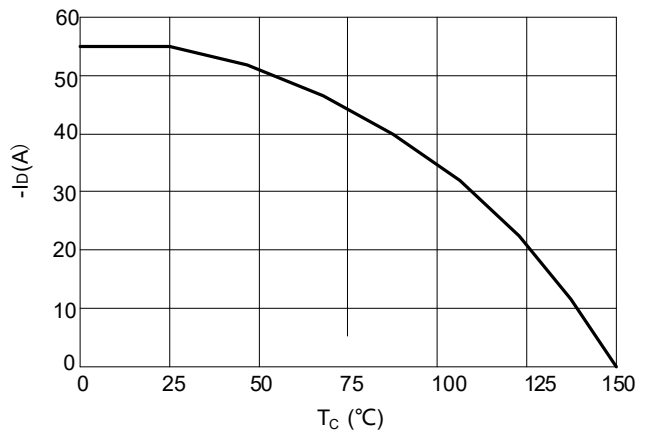
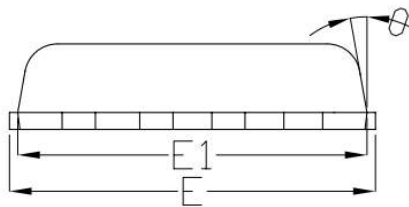
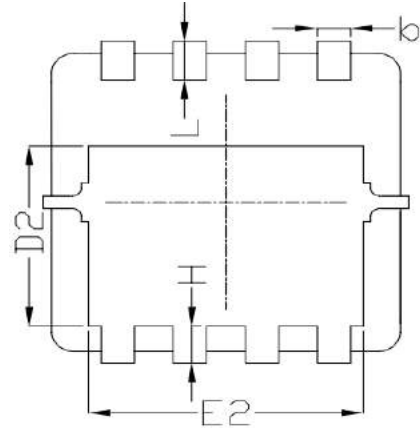
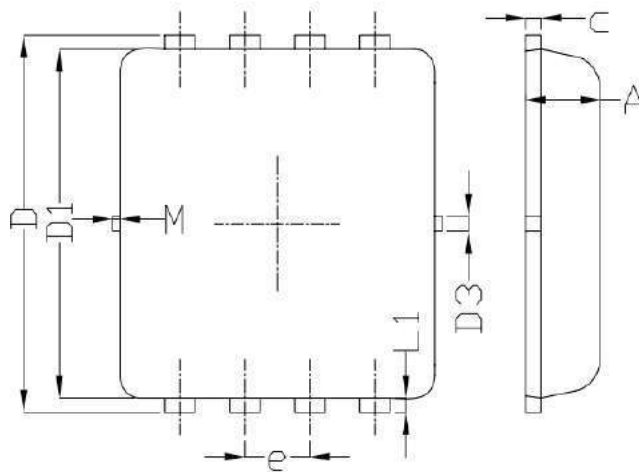
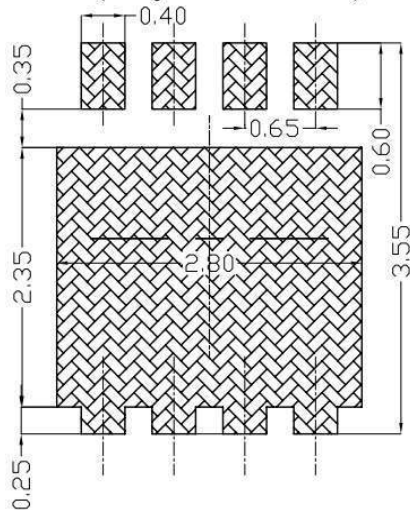


Figure 10: Maximum Continuous Drain Current vs. Case Temperature

■ PDFN3X3 PACKAGE OUTLINE DIMENSIONS



Land Pattern
(Only for Reference)



SYMBOL	DIMENSIONAL REQMTS		
	MIN	NOM	MAX
A	0.70	0.75	0.80
b	0.25	0.30	0.35
c	0.10	0.15	0.25
D	3.25	3.35	3.45
D1	3.00	3.10	3.20
D2	1.78	1.88	1.98
D3	---	0.13	---
E	3.20	3.30	3.40
E1	3.00	3.15	3.20
E2	2.39	2.49	2.59
e	0.65BSC		
H	0.30	0.39	0.50
L	0.30	0.40	0.50
L1	---	0.13	---
θ	---	10°	12°
M	*	*	0.15
* Not specified			